



US 20080212245A1

(19) **United States**(12) **Patent Application Publication**
Choi(10) **Pub. No.: US 2008/0212245 A1**(43) **Pub. Date: Sep. 4, 2008**(54) **ELECTROSTATIC DISCHARGE DEVICE AND
ORGANIC ELECTRO-LUMINESCENCE
DISPLAY DEVICE HAVING THE SAME****Publication Classification**

- (51) **Int. Cl.**
G09G 3/32 (2006.01)
H01L 51/50 (2006.01)
H02H 9/04 (2006.01)
- (52) **U.S. Cl.** 361/56; 345/83; 257/59; 257/E51.022
- (57) **ABSTRACT**

(76) **Inventor:** Hee Dong Choi, Seosan-si (KR)

Correspondence Address:
MCKENNA LONG & ALDRIDGE LLP
1900 K STREET, NW
WASHINGTON, DC 20006 (US)

(21) **Appl. No.:** 12/005,359(22) **Filed:** Dec. 27, 2007(30) **Foreign Application Priority Data**

Dec. 28, 2006 (KR) 10-2006-0135873

An electrostatic discharge device and an organic electro-luminescence display device having the same are provided. The organic electro-luminescence display device includes an electrostatic discharge device including a metal pattern having an island shape on a substrate, an insulating layer on the metal pattern, a semiconductor pattern on the insulating layer, the semiconductor pattern corresponding to the metal pattern, a first electrode overlapping one end of the semiconductor pattern, and a second electrode overlapping the other end of the semiconductor pattern, and spaced from the first electrode, thereby preventing a current leakage, a signal distortion and a signal cross-talk to improve the reliability.

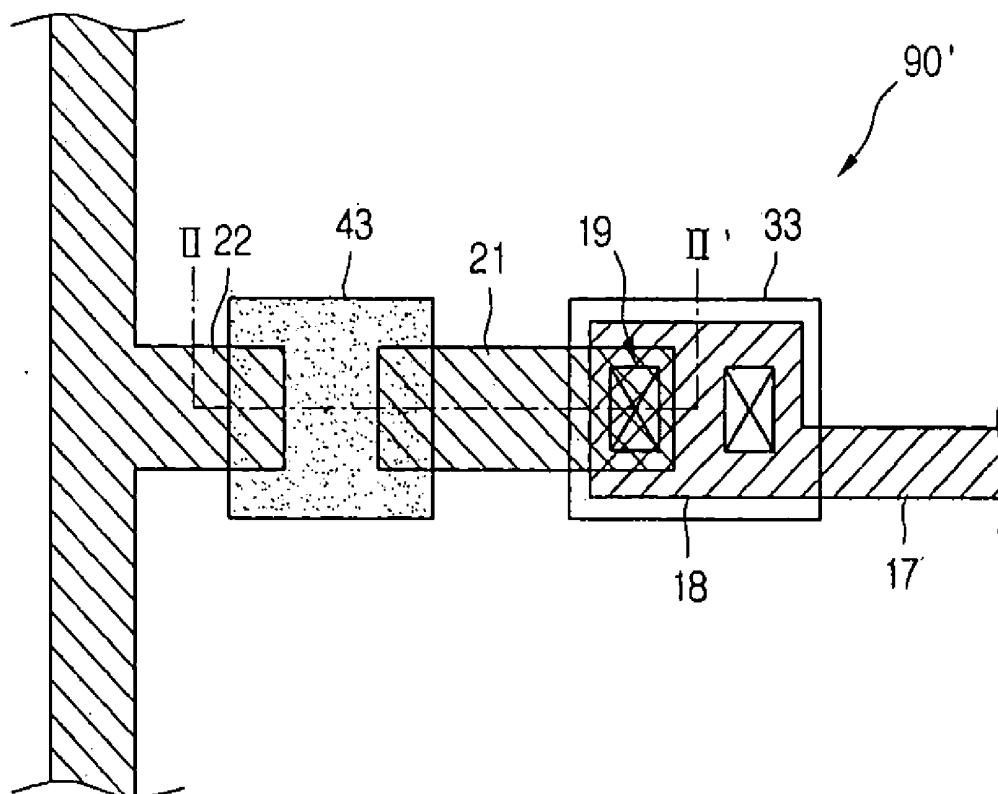


Fig. 1

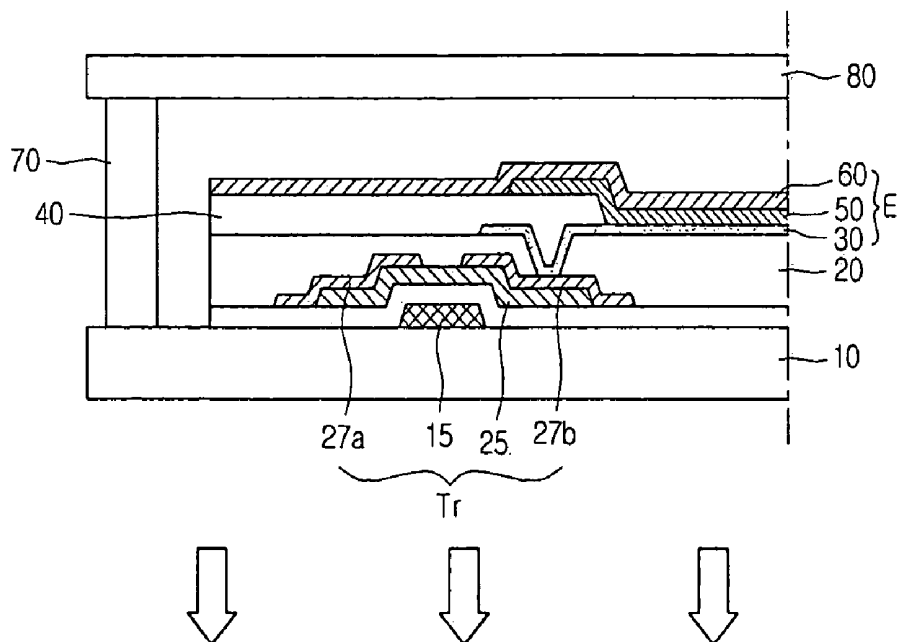


Fig. 2

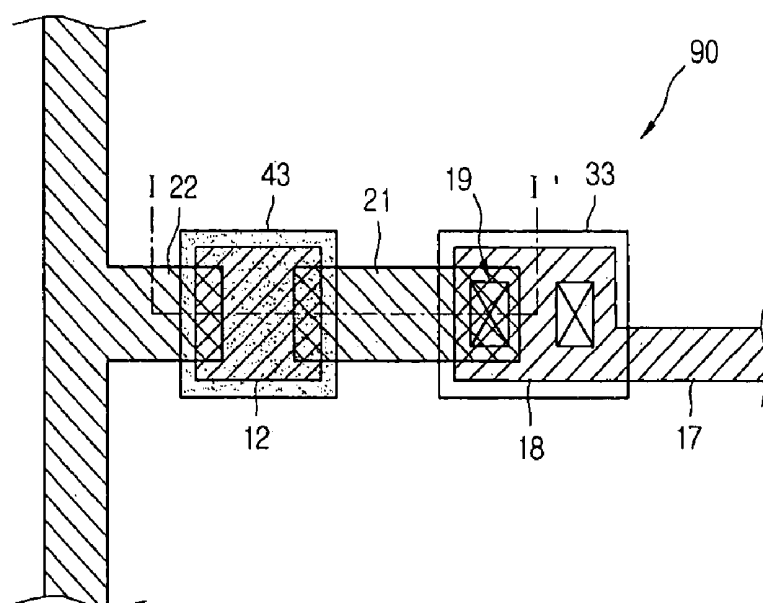


Fig. 3

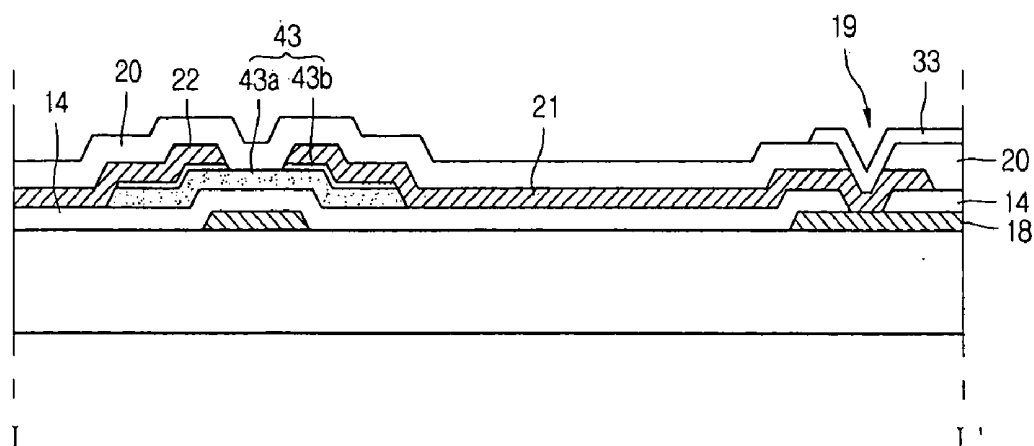


Fig. 4

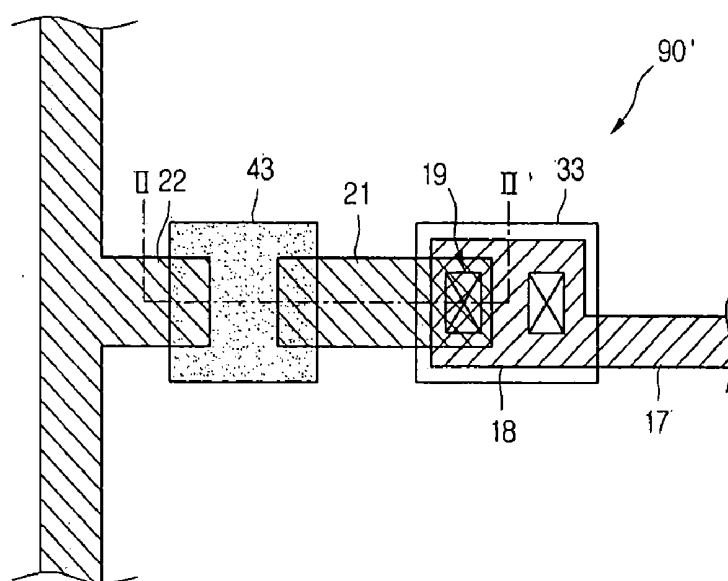
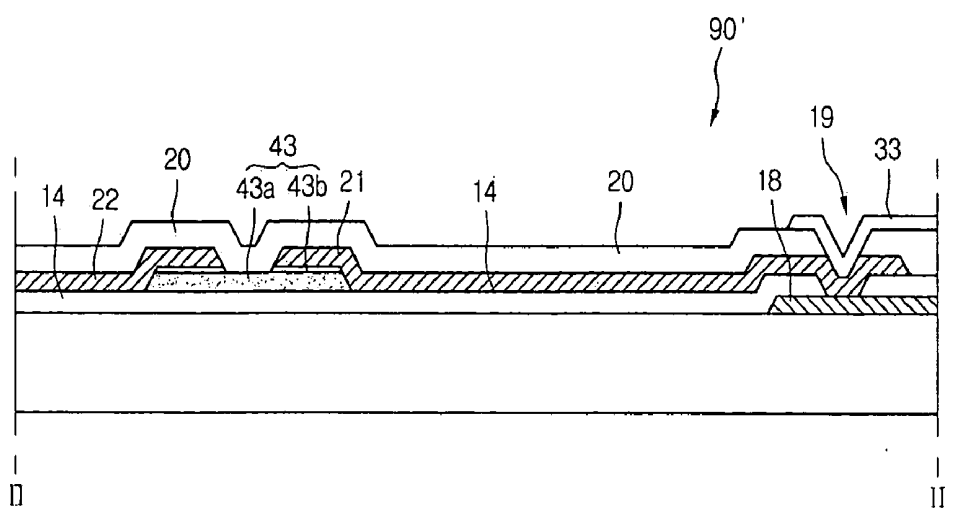


Fig. 5



**ELECTROSTATIC DISCHARGE DEVICE AND
ORGANIC ELECTRO-LUMINESCENCE
DISPLAY DEVICE HAVING THE SAME**

[0001] This application claims the benefit of Korea Patent Application No. 10-2006-0135873, filed on Dec. 28, 2006, which is hereby incorporated by reference for all purposes as if fully set forth herein.

BACKGROUND OF THE INVENTION

[0002] 1. Field of the Invention

[0003] The present invention relates to an electrostatic discharge device, and more particularly, to an organic electro-luminescence display device having the same.

[0004] 2. Discussion of the Related Art

[0005] A cathode ray tube (CRT) has been widely used for a display device such as a television and a monitor. However, the CRT has some limitations such as heavy weight and large size, and a high driving voltage. For this reason, a flat panel display having many advantages of a lightweight slim profile and low power consumption has come to the front in recent years. Many researches for developing various flat panel displays such as a liquid crystal display (LCD) device, a plasma display panel (PDP), a field emission display (FED) and an organic electro-luminescence diode (also referred to as an electro-luminescence diode; ELD) have been carried out.

[0006] The organic electro-luminescence display device is in the limelight as a display device that can display natural colors since the organic electro-luminescence display device can emit light in an entire visible region. Also, the organic electro-luminescence display device has high brightness and a low operation voltage characteristic. The organic electro-luminescence display device is a self-luminous display device, and therefore has a high contrast ratio. Also, the organic electro-luminescence display device can be realized as an ultra-thin display device using a simple process, and generates small pollution to the environment. Also, since the organic electro-luminescence display device has a response time of several micro seconds (μ s), it is suitable for displaying a moving image. The organic electro-luminescence display device has no limitation of a viewing angle. Furthermore, the organic electro-luminescence display device is stable at a low temperature. Since the organic electro-luminescence display device may be driven at a low direct current voltage of about 5 V to 15 V, it is easy to manufacture and design a driving circuit of the organic electro-luminescence display device.

[0007] The organic electro-luminescence display device includes a plurality of pixels arranged in a matrix configuration to reduce a drive voltage and improve image quality. The plurality of the pixels are defined by a plurality of gate lines crossing a plurality of data lines. In this case, an active matrix connecting a switching device and a driving device to each pixel is applied to the organic electro-luminescence display device.

[0008] A substrate is provided to manufacture an active matrix organic electro-luminescence display device. Thereafter, a plurality of lines, a switching device and a driving device, a first electrode, an organic emission layer and a second electrode are formed on the substrate. At this point, the substrate is fixed to a robot arm and transferred to a corresponding processing unit. The substrate may contact the robot arm and other equipments frequently, so that a static electricity may be generated to the substrate. The static electricity

may cause an electrical defect such as disconnection and short circuit, causing a critical damage to the lines (gate lines, data lines, etc.) formed on the substrate.

SUMMARY OF THE INVENTION

[0009] Accordingly, the present invention is directed to electrostatic discharge device and organic electro-luminescence display device having the same that substantially obviates one or more of the problems due to limitations and disadvantages of the related art.

[0010] An advantage of the present invention is to provide an electrostatic discharge device for effectively removing static electricity and easily being designed.

[0011] Another advantage of the present invention is to provide an organic electro-luminescence display device for effectively removing and preventing damages and defects of a panel.

[0012] Additional features and advantages of the invention will be set forth in the description which follows, and in part will be apparent from the description, or may be learned by practice of the invention. The objectives and other advantages of the invention will be realized and attained by the structure particularly pointed out in the written description and claims hereof as well as the appended drawings.

[0013] To achieve these and other advantages and in accordance with the purpose of the invention, as embodied and broadly described, an electrostatic discharge device includes: a metal pattern having an island shape on a substrate; an insulating layer on the metal pattern; a semiconductor pattern on the insulating layer, the semiconductor pattern corresponding to the metal pattern; a first electrode overlapping one end of the semiconductor pattern; and a second electrode overlapping the other end of the semiconductor pattern, and spaced from the first electrode.

[0014] In another aspect of the present invention, an electrostatic discharge device includes: an insulating layer on a substrate; a semiconductor pattern on the insulating layer; a first electrode overlapping one end of the semiconductor pattern; and a second electrode overlapping the other end of the semiconductor pattern and spaced from the first electrode.

[0015] In yet another aspect of the present invention, an organic electro-luminescence display device includes: a first substrate where an image display region and an image non-display region are defined; at least one thin film transistor in a pixel region defined by a gate line and a data line crossing each other in the image display region; an electrostatic discharge device in the image non-display region, the electrostatic discharge device being on one end of the gate line; and an organic light emitting device on the image display region, the electrostatic discharge device including: a metal pattern having an island shape on the substrate; an insulating layer on the metal pattern; a semiconductor pattern on the insulating layer, the semiconductor pattern corresponding to the metal pattern; a first electrode overlapping one end of the semiconductor pattern and connected to the gate line; and a second electrode overlapping the other end of the semiconductor pattern, and spaced from the first electrode.

[0016] In yet another aspect of the present invention, an organic electro-luminescence display device includes: a first substrate where a image display region and image non-display region are defined; at least one film transistor on a pixel region defined by a gate line and a data line crossing each other; an electrostatic discharge device on the image non-display region and one end of the gate line; and an organic

light emitting device on the image display region, wherein the electrostatic discharge device includes: an insulating layer on the substrate; a semiconductor pattern on the insulating layer; a first electrode overlapping one end of the semiconductor pattern and connected to the gate line; and a second electrode overlapping the other end of the semiconductor pattern, and spaced from the first electrode.

[0017] It is to be understood that both the foregoing general description and the following detailed description are exemplary and are intended to provide further explanation of the invention as claimed.

BRIEF DESCRIPTION OF THE DRAWINGS

[0018] The accompanying drawings, which are included to provide a further understanding of the invention and are incorporated in and constitute a part of this specification, illustrate embodiments of the invention and together with the description serve to explain the principles of the invention.

[0019] In the drawings:

[0020] FIG. 1 is a cross sectional view illustrating an organic electro-luminescence display device according to the present disclosure.

[0021] FIG. 2 is a plan view illustrating an electrostatic discharge device formed between one end of a gate line and a shorting bar according to an embodiment.

[0022] FIG. 3 is a cross sectional view illustrating an electrostatic discharge device taken along line I-I' in FIG. 2.

[0023] FIG. 4 is a plan view illustrating an electrostatic discharge device formed between one end of a gate line and a shorting bar according to another embodiment.

[0024] FIG. 5 is a cross sectional view illustrating an electrostatic discharge device taken along line II-II' in FIG. 4.

DETAILED DESCRIPTION OF THE ILLUSTRATED EMBODIMENTS

[0025] Reference will now be made in detail to embodiments of the present invention, examples of which are illustrated in the accompanying drawings.

[0026] Hereinafter, an organic electro-luminescence display device will be fully described with reference to the accompanying drawings.

[0027] FIG. 1 is a cross sectional view illustrating an organic electro-luminescence display device according to the present disclosure, which illustrating a cross sectional structure of an active matrix type operated in a bottom light emitting method.

[0028] However, a static electricity preventing pattern according to the present disclosure is applicable to an organic electro-luminescence display device of an active matrix type operated in a top emitting method, and is also applicable to an organic electro-luminescence display device of which a organic light emitting device and array devices are respectively formed in different substrates.

[0029] Referring to FIG. 1, a thin film transistor (TFT) Tr is formed on a substrate 10. The TFT Tr includes a gate electrode 15, an active layer 25, a source electrodes 27a, and a drain electrode 27b.

[0030] The substrate 10 includes a passivation layer 20 having a contact hole exposing a portion of the drain electrode 27b.

[0031] A first electrode 30 is formed on the passivation layer 20, and is electrically connected to the drain electrode 27b via the contact hole.

[0032] An insulating layer 40 where a sub-pixel region is defined is disposed on the first electrode 30. An organic emission layer 50 is disposed on the first electrode 30 of the sub-pixel region. A second electrode 60 serving as a common electrode is disposed on the organic emission layer 50. Here, the first and second electrodes 30 and 60 apply an electric field to the organic emission layer 50 so that the organic emission layer 50 can emit light.

[0033] After a sealant 70 is coated on an outer edge of the substrate 10 in order to protect the organic light-emitting diode device E formed on the substrate 10 from external humidity and oxygen, an encapsulating substrate 80 is attached to face the organic light-emitting diode device E, so that the organic electro-luminescence display device can be manufactured.

[0034] During the manufacturing process of the substrate having the TFT, a high voltage such as static electricity may be generated inside or outside the device. Accordingly, only when the high voltage is appropriately removed, it is possible to manufacture a normal organic electro-luminescence display device.

[0035] FIG. 2 is a plan view illustrating an electrostatic discharge device formed between one end of a gate line and a shorting bar according to an embodiment. FIG. 3 is a cross sectional view illustrating an electrostatic discharge device taken along line I-I' in FIG. 2.

[0036] Although the electrostatic discharge device is disposed on one end of a gate line illustrated in FIG. 2, the electrostatic discharge device may be also disposed on one end of a data line.

[0037] Referring to FIGS. 2 and 3, an electrostatic discharge device 90 according to an embodiment includes a first electrode 21, a second electrode 22, a semiconductor pattern 43 and a floating gate electrode 12. The first electrode 21 is connected to a gate pad 18 formed on one end of a gate line 17. The second electrode 22 is spaced from the first electrode 21, and is connected a shorting bar. The semiconductor pattern 43 is formed between the first electrode 21 and the second electrode 22. The floating gate electrode 12 is formed under the semiconductor pattern 43.

[0038] A transparent 33 may be further formed on the gate pad 18. The first electrode 21 is connected to the gate pad 18 via the contact hole 19 exposing a predetermined portion of the gate pad 18.

[0039] A first insulating layer 14 is formed between the first floating gate electrode 12 and the semiconductor pattern 43.

[0040] The floating gate electrode 12 may be formed in the same process as the process of forming the gate electrode 15.

[0041] A floating voltage is applied to the floating gate electrode 12

[0042] The first and second electrodes 21 and 22 overlap both ends of the semiconductor pattern 43.

[0043] The first and second electrodes 21 and 22 may be formed in the same process as the process of forming the source and drain electrodes 27a and 27b.

[0044] The semiconductor pattern 43 may be formed in the same process as the process of forming the active layer 25.

[0045] The semiconductor pattern 43 includes a first semiconductor pattern 43a and a second semiconductor pattern 43b. The second semiconductor pattern 43b formed of amorphous silicon layer is stacked on the first semiconductor pattern 43a formed of amorphous silicon layer implanted with impurities.

[0046] The second semiconductor pattern **43b** may be formed on an exposed region between the first electrode **21** and the second electrode **22**. Also, the second semiconductor pattern **43b** may be etched to remain only under the first and second electrodes **21** and **22**.

[0047] When a high voltage such as static electricity is applied to the first electrode **21** or the second electrode **22**, electric charges of the semiconductor pattern **43** are concentrated on an electrode where a higher voltage is applied, thereby forming a channel. The static electricity is discharged through the channel.

[0048] Since only a general signal of the general gate line **17** or the data line may not operate the electrostatic discharge device **90**, a risk of current leakage does not exist. Also, since a semiconductor pattern of the electrostatic discharge device serves as a channel during occurrence of the static electricity with high voltage, the static electricity can be discharged through the shorting bar.

[0049] The electrostatic discharge device may be operated only when the static electricity occurs, thereby preventing defects due to the static electricity. Also, the organic electro-luminescence display device provided with the electrostatic discharge device can prevent deterioration of image quality, and reduce consumption of electric power.

[0050] Furthermore, the organic electro-luminescence display device according to the present disclosure can prevent a current leakage, a signal distortion and a signal cross-talk to improve the reliability.

[0051] FIG. 4 is a plan view illustrating an electrostatic discharge device formed between one end of a gate line and a shorting bar according to another embodiment. FIG. 5 is a cross sectional view illustrating an electrostatic discharge device taken along line II-II' in FIG. 4.

[0052] Although the electrostatic discharge device is disposed on one end of a gate line illustrated in FIG. 2, the electrostatic discharge device may be disposed on one end of a data line.

[0053] Referring to FIGS. 4 and 5, an electrostatic discharge device **90'** according to another embodiment includes a first electrode **21**, a second electrode **22** and a semiconductor pattern **43**. The first electrode **21** is connected to a gate pad **18** formed on one end of a gate line **17**. The second electrode **22** is spaced from the first electrode **21**, and is connected a shorting bar. The semiconductor pattern **43** is formed between the first electrode **21** and the second electrode **22**.

[0054] The first and second electrodes **21** and **22** overlap both ends of the semiconductor pattern **43**.

[0055] The semiconductor pattern **43** includes a first semiconductor pattern **43a** and a second semiconductor pattern **43b**. The second semiconductor pattern **43b** formed of amorphous silicon layer is stacked on the first semiconductor pattern **43a** formed of amorphous silicon layer implanted with impurities.

[0056] The second semiconductor pattern **43b** may be formed on an exposed region between the first electrode **21** and the second electrode **22**. Also, the second semiconductor pattern **43b** may be etched to remain only under the first and second electrodes **21** and **22**.

[0057] When a high voltage such as static electricity is applied to the first electrode **21** or the second electrode **22**, electric charges of the semiconductor pattern **43** are concentrated on an electrode where a higher voltage is applied, thereby forming a channel. The static electricity is discharged through the channel.

[0058] Since only a general signal of the general gate line **17** or the data line may not operate the electrostatic discharge device **90'**, a risk of current leakage does not exist. Also, since a semiconductor pattern of the electrostatic discharge device serves as a channel during existence of the static electricity with high voltage, the static electricity can be discharged through the shorting bar.

[0059] Since the electrostatic discharge devices **90** and **90'** according to the first and second embodiments has a design area smaller than a prior art electrostatic discharge device, extra area can be converted into a Vss region or a Vdd region.

[0060] Also, although a signal applied to a gate line or a data line has a voltage within a range of approximately 15V to a static electricity voltage, a channel of the electrostatic discharge device will not be opened, thereby preventing applying an unnecessary signal to the gate line in the panel. Accordingly, it is possible to prevent deterioration of image quality, and to reduce consumption of electric power due to a current leakage.

[0061] The electrostatic discharge device may be operated only when the static electricity occurs, thereby preventing defects due to the static electricity. Also, the organic electro-luminescence display device provided with the electrostatic discharge device can prevent deterioration of image quality, and reduce consumption of electric power.

[0062] Furthermore, the organic electro-luminescence display device according to the present disclosure can prevent a current leakage, a signal distortion and a signal cross-talk to improve the reliability.

[0063] Any reference in this specification to "one embodiment," "an embodiment," "exemplary embodiment," etc., means that a particular feature, structure, or characteristic described in connection with the embodiment is included in at least one embodiment of the disclosure. The appearances of such phrases in various places in the specification are not necessarily all referring to the same embodiment. Further, when a particular feature, structure, or characteristic is described in connection with any embodiment, it is submitted that it is within the purview of one skilled in the art to effect such feature, structure, or characteristic in connection with others of the embodiments.

[0064] It will be apparent to those skilled in the art that various modifications and variations can be made in the present invention without departing from the spirit or scope of the invention. Thus, it is intended that the present invention cover the modifications and variations of this invention provided they come within the scope of the appended claims and their equivalents.

What is claimed is:

1. An electrostatic discharge device comprising:
 - a metal pattern having an island shape on a substrate;
 - an insulating layer on the metal pattern;
 - a semiconductor pattern on the insulating layer, the semiconductor pattern corresponding to the metal pattern;
 - a first electrode overlapping one end of the semiconductor pattern; and
 - a second electrode overlapping the other end of the semiconductor pattern, and spaced from the first electrode.
2. The electrostatic discharge device according to claim 1, wherein the semiconductor pattern comprises:
 - a first semiconductor pattern formed of an amorphous silicon layer; and

- a second semiconductor pattern on the first semiconductor pattern, the second semiconductor pattern being formed of an amorphous silicon layer doped with impurities.
3. An electrostatic discharge device comprising:
an insulating layer on a substrate;
a semiconductor pattern on the insulating layer;
a first electrode overlapping one end of the semiconductor pattern; and
a second electrode overlapping the other end of the semiconductor pattern and spaced from the first electrode.
4. The electrostatic discharge device according to claim 3, wherein the semiconductor pattern comprises:
a first semiconductor pattern formed of an amorphous silicon layer; and
a second semiconductor pattern on the first semiconductor pattern, the second semiconductor pattern being formed of an amorphous silicon layer doped with impurities.
5. An organic electro-luminescence display device comprising:
a first substrate where an image display region and an image non-display region are defined;
at least one thin film transistor in a pixel region defined by a gate line and a data line crossing each other in the image display region;
an electrostatic discharge device in the image non-display region, the electrostatic discharge device being on one end of the gate line; and
an organic light emitting device on the image display region, the electrostatic discharge device comprising:
a metal pattern having an island shape on the substrate;
an insulating layer on the metal pattern;
a semiconductor pattern on the insulating layer corresponding to the metal pattern;
a first electrode overlapping one end of the semiconductor pattern and connected to the gate line; and
a second electrode overlapping the other end of the semiconductor pattern and spaced from the first electrode.
6. The organic electro-luminescence display device according to claim 5, wherein the thin film transistor comprises:
a gate electrode on the substrate, the gate electrode being formed in the same layer as that of the metal pattern and connected to the gate line;
the insulating layer on the gate electrode;
a semiconductor pattern on the insulating layer, the semiconductor pattern corresponding to the gate electrode;
a source electrode overlapping one end of the semiconductor pattern and connected to the data line; and
a drain electrode overlapping the other end of the semiconductor pattern and spaced from the source electrode.
7. The organic electro-luminescence display device according to claim 5, further comprising a shorting bar on the non-display region, the shorting bar being connected to the second electrode.
8. The organic electro-luminescence display device according to claim 5, wherein the semiconductor pattern comprises:
a first semiconductor pattern formed of an amorphous silicon layer; and
a second semiconductor pattern on the first semiconductor pattern, the second semiconductor pattern being formed of an amorphous silicon layer doped with impurities.
9. The organic electro-luminescence display device according to claim 5, further comprising an electrostatic discharge device in the image non-display region, the electrostatic discharge device being on one end of the data line, wherein the electrostatic discharge device comprises:
a metal pattern having an island shape on the substrate;
an insulating layer on the metal pattern;
a semiconductor pattern on the insulating layer, the semiconductor pattern corresponding to the metal pattern;
a first electrode overlapping one end of the semiconductor pattern and connected to the gate line; and
a second electrode overlapping the other end of the semiconductor pattern, and spaced from the first electrode.
10. An organic electro-luminescence display device comprising:
a first substrate where an image display region and an image non-display region are defined;
at least one film transistor on a pixel region defined by a gate line and a data line crossing each other;
an electrostatic discharge device in the image non-display region, the electrostatic discharge device being on one end of the gate line; and
an organic light emitting device on the image display region, wherein the electrostatic discharge device comprises:
an insulating layer on the substrate;
a semiconductor pattern on the insulating layer;
a first electrode overlapping one end of the semiconductor pattern and connected to the gate line; and
a second electrode overlapping the other end of the semiconductor pattern and spaced from the first electrode.
11. The organic electro-luminescence display device according to claim 10, wherein the thin film transistor comprises:
a gate electrode on the substrate, the gate electrode being formed in the same layer as that of the metal pattern and connected to the gate line;
the insulating layer on the gate electrode;
a semiconductor pattern on the insulating layer, the semiconductor pattern corresponding to the gate electrode;
a source electrode overlapping one end of the semiconductor pattern and connected to the data line; and
a drain electrode overlapping the other end of the semiconductor pattern and spaced from the source electrode.
12. The organic electro-luminescence display device according to claim 10, further comprising a shorting bar on the non-display region, the shorting bar being connected to the second electrode.
13. The organic electro-luminescence display device according to claim 10, wherein the semiconductor pattern comprises:
a first semiconductor pattern formed of an amorphous silicon layer; and
a second semiconductor pattern on the first semiconductor pattern, the second semiconductor pattern being formed of an amorphous silicon layer doped with impurities.
14. The organic electro-luminescence display device according to claim 10, further comprising an electrostatic discharge device in the image non-display region, the electrostatic discharge device being on one end of the data line, wherein the electrostatic discharge device comprises:
a metal pattern having an island shape on the substrate;
an insulating layer on the metal pattern;
a semiconductor pattern on the insulating layer, the semiconductor pattern corresponding to the metal pattern;
a first electrode overlapping one end of the semiconductor pattern and connected to the gate line; and
a second electrode overlapping the other end of the semiconductor pattern, and spaced from the first electrode.

专利名称(译)	静电放电装置和具有该装置的有机电致发光显示装置		
公开(公告)号	US20080212245A1	公开(公告)日	2008-09-04
申请号	US12/005359	申请日	2007-12-27
[标]申请(专利权)人(译)	CHOI HEE董		
申请(专利权)人(译)	CHOI HEE董		
当前申请(专利权)人(译)	CHOI HEE董		
[标]发明人	CHOI HEE DONG		
发明人	CHOI, HEE DONG		
IPC分类号	G09G3/32 H01L51/50 H02H9/04		
CPC分类号	G09G2330/04 H01L27/0296 H05B33/14 H01L27/0266 H01L27/3244		
优先权	1020060135873 2006-12-28 KR		
其他公开文献	US8637867		
外部链接	Espacenet USPTO		

摘要(译)

提供一种静电放电装置和具有该静电放电装置的有机电致发光显示装置。该有机电致发光显示装置包括静电放电装置，该静电放电装置包括在基板上具有岛状的金属图案，在该金属图案上的绝缘层，在该绝缘层上的半导体图案，与该金属图案对应的半导体图案，第一电极与半导体图案的一端重叠，第二电极与半导体图案的另一端重叠，并与第一电极隔开，从而防止电流泄漏，信号失真和信号串扰，从而提高可靠性。

